



MDL-III-830R/1~500mW



INFRARED DIODE LASER
AT 830nm

Infrared diode laser at 830nm features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are widely used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Wavelength (nm)	830±10	
Operating mode	CW	
Output power (mW)	>1,10,20,..., 200	>200,210, ... ,500
Power stability (rms, over 4 hours)	<1%, <3%, <5%	
Transverse mode	Round	
Beam diameter at the aperture (mm)	~2	~2
Beam divergence, full angle (mrad)	<8	<18
Warm-up time (minutes)	<5	
Beam height from base plate (mm)	24.8	
Operating temperature (°C)	10~35	
Power supply	85-264VAC	PSU-III-LED/ PSU-III-FDA (Frequency for 1Hz-30kHz)
	100-240VAC	PSU-A-D (Frequency for 30kHz -100kHz)
TTL / Analog modulation	TTL or Analog with 1Hz-1kHz 1kHz-10kHz, 10kHz-30kHz, 30kHz-100kHz optional	
Expected lifetime (hours)	10000	
Warranty	1 year	



MDL-III-830R	PSU-III-LED	PSU-III-FDA	PSU-A-D
<p>143.5(L)×73(W)×46.2(H) mm³, 0.7kg</p>	<p>188.6 (L) ×155(W) ×92 (H) mm³, 1.5kg</p>	<p>171(L) ×130(W) ×62.2 (H) mm³, 1.2kg</p>	<p>162(L) ×144(W) ×70 (H) mm³, 1.0kg</p>